

# PMEG2010AEJ

20 V, 1 A very low V<sub>F</sub> MEGA Schottky barrier rectifier in SOD323F package

Rev. 03 — 15 January 2010 Product date

Product data sheet

## **Product profile**

#### 1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD323F (SC-90) very small and flat lead Surface Mounted Device (SMD) plastic package.

#### 1.2 Features

■ Forward current: ≤ 1 A

■ Reverse voltage: ≤ 20 V

Very low forward voltage

Very small and flat lead SMD plastic package

#### 1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Inverse polarity protection
- Low power consumption applications

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>F</sub>	forward current	$T_{sp} \le 55  ^{\circ}C$	-	-	1	Α
V <sub>R</sub>	reverse voltage		-	-	20	V
V <sub>F</sub>	forward voltage	$I_F = 1000 \text{ mA}$	<u>[1]</u> _	480	550	mV

[1] Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .



## 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Symbol
1	cathode	[1]	. 84
2	anode	1 2	1 🔁 2
			sym001

<sup>[1]</sup> The marking bar indicates the cathode.

## 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PMEG2010AEJ	SC-90	plastic surface mounted package; 2 leads	SOD323F

## 4. Marking

Table 4. Marking codes

Type number	Marking code
PMEG2010AEJ	EM

## 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_R$	reverse voltage		-	20	V
I <sub>F</sub>	forward current	T <sub>sp</sub> ≤ 55 °C	-	1	А
I <sub>FRM</sub>	repetitive peak forward current	$t_p \leq 1 \text{ ms; } \delta \leq 0.25$	-	5.5	Α
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; $t_p = 8 \text{ ms}$	-	10	Α
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	[1] -	360	mW
			[2] _	830	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

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#### Thermal characteristics 6.

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2]	-	-	350	K/W
			[1][3]	-	-	150	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		[4]	-	-	55	K/W

<sup>[1]</sup> For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses. Nomograms for determining the reverse power losses  $P_R$  and  $I_{F(AV)}$  rating are available on request.

- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.
- Solder point of cathode tab.

#### 7. **Characteristics**

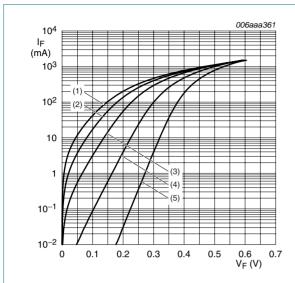
**Product data sheet** 

**Characteristics** 

 $T_{amb} = 25$  °C unless otherwise specified.

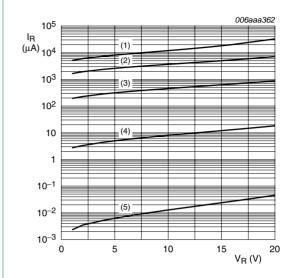
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{F}$	forward voltage		<u>[1]</u>			
	I <sub>F</sub> = 10 mA	-	240	270	mV	
	I <sub>F</sub> = 100 mA	-	300	350	mV	
	$I_F = 500 \text{ mA}$	-	400	460	mV	
		$I_F = 1000 \text{ mA}$	-	480	550	mV
I <sub>R</sub> reverse cur	reverse current	$V_R = 5 V$	-	5	10	μΑ
		$V_R = 8 V$	-	7	20	μΑ
		V <sub>R</sub> = 10 V	-	8	30	μΑ
		$V_R = 15 V$	-	10	50	μΑ
		V <sub>R</sub> = 20 V	-	15	70	μΑ
$C_{d}$	diode capacitance	$V_R = 1 V$ ; $f = 1 MHz$	-	40	50	pF

<sup>[1]</sup> Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .



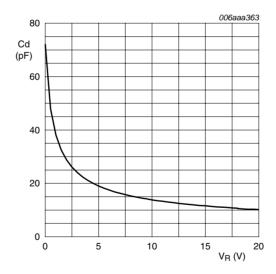
- (1)  $T_{amb} = 150 \, ^{\circ}C$
- (2)  $T_{amb} = 125 \, ^{\circ}C$
- (3)  $T_{amb} = 85 \, ^{\circ}C$
- (4)  $T_{amb} = 25 \, ^{\circ}C$
- (5)  $T_{amb} = -40 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



- (1)  $T_{amb} = 150 \, ^{\circ}C$
- (2)  $T_{amb} = 125 \, ^{\circ}C$
- (3)  $T_{amb} = 85 \, ^{\circ}C$
- (4)  $T_{amb} = 25 \, ^{\circ}C$
- (5)  $T_{amb} = -40 \, ^{\circ}C$

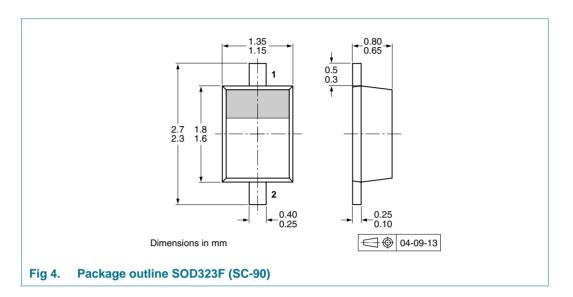
Fig 2. Reverse current as a function of reverse voltage; typical values



 $T_{amb} = 25 \, ^{\circ}C; f = 1 \, MHz$ 

Fig 3. Diode capacitance as a function of reverse voltage; typical values

#### 8. Package outline



## 9. Packing information

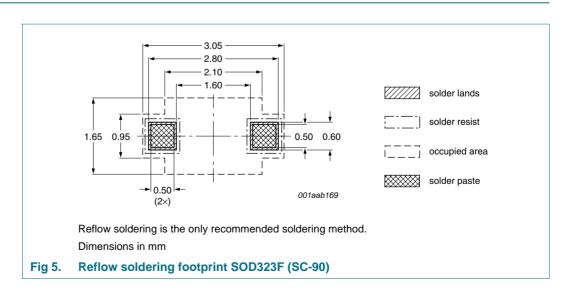
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity	
			3000	10000
PMEG2010AEJ	SOD323F	4 mm pitch, 8 mm tape and reel	-115	-135

[1] For further information and the availability of packing methods, see Section 14.

## 10. Soldering

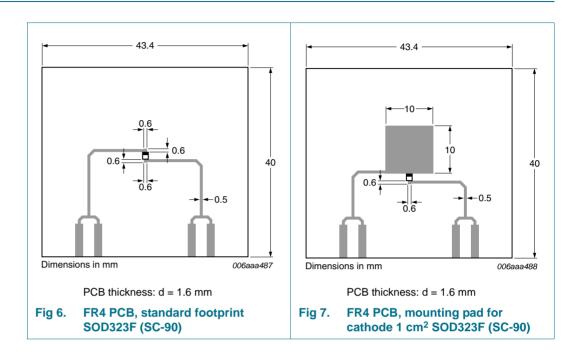


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## 11. Mounting

**Product data sheet** 





# 12. Revision history

#### Table 9. Revision history

	•			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG2010AEJ_3	20100115	Product data sheet	-	PMEG2010AEJ_2
Modifications:		eet was changed to reflect w legal definitions and disc		
PMEG2010AEJ_2	20051014	Product data sheet	-	PMEG2010AEJ_1
PMEG2010AEJ_1	20050302	Product data sheet	-	-

## 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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